

Description

The AM3930N uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

D2 S1 D1 S2 G2

SOT-23-6L

General Features

V_{DS} = 30V I_D = 4.5A

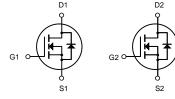
 $R_{DS(ON)} < 38m\Omega$ @ $V_{GS}=10 V$

Application

Battery protection

Load switch

Uninterruptible power supply



Dual N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AM3930N	SOT-23-6L	6800 XXX YYYY	3000

Absolute Maximum Ratings@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	30	V
V _G s	Gate-Source Voltage <u>+20</u>		V
I _D @T _A =25°C	Drain Current, V _{GS} @ 4.5V ³	4.5	А
Ірм	Pulsed Drain Current ¹	15	А
P _D @T _A =25°C	Total Power Dissipation	1.25	W
Тѕтс	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
Rthj-a	Maximum Thermal Resistance, Junction- ambient ³	125	°C/W



Electrical Characteristics (T_J=25°C unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characteristic						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250µA	30	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V,	-	-	1.0	μA
I _{GSS}	Gate to Body Leakage Current	V _{DS} =0V, V _{GS} = ±20V	-	_	±100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.5	V
Б	Static Drain-Source on-Resistance	V _{GS} =10V, I _D =4A	-	29	38	0
$R_{DS(on)}$		V _{GS} =4.5V, I _D =3A	-	45	65	mΩ
Dynamic C	Characteristics		•			
C _{iss}	Input Capacitance	\\\\ 45\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-	233	_	pF
Coss	Output Capacitance	V _{DS} =15V, V _{GS} =0V,	-	44	-	рF
C _{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	33	-	рF
Qg	Total Gate Charge	\/ -45\/ -24	-	3	-	nC
Q _{gs}	Gate-Source Charge	V_{DS} =15V, I_{D} =2A, V_{GS} =10V	-	0.5	-	nC
Q_gd	Gate-Drain("Miller") Charge	VGS-10V	-	0.8	_	nC
Switching	Characteristics					
t _{d(on)}	Turn-on Delay Time	\\\ 45\\	-	4	-	ns
t _r	Turn-on Rise Time	V _{DS} =15V,	-	2.1	-	ns
$t_{d(off)}$	Turn-off Delay Time	I_D =4A, R_{GEN} =3 Ω , V_{GS} =10V	-	15	-	ns
t_{f}	Turn-off Fall Time	VGS-10V	-	3.2	-	ns
Drain-Soul	rce Diode Characteristics and Maxim	um Ratings				
Is	Maximum Continuous Drain to Source Diode Forward Current		-	-	4.5	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	16	Α
V_{SD}	Drain to Source Diode Forward Voltage	ward V _{GS} =0V, I _S =4A		-	1.2	٧

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

^{2.} Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



Typical Performance Characteristics

Figure1: Output Characteristics

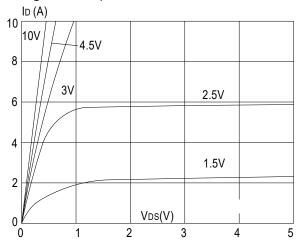


Figure 3:On-resistance vs. Drain Current

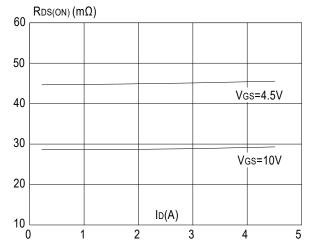


Figure 5: Gate Charge Characteristics

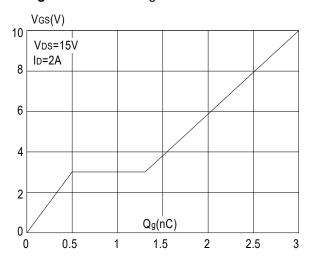


Figure 2: Typical Transfer Characteristics

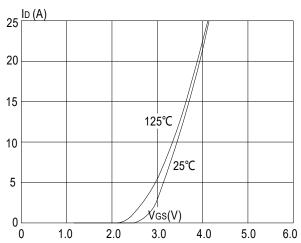


Figure 4: Body Diode Characteristics

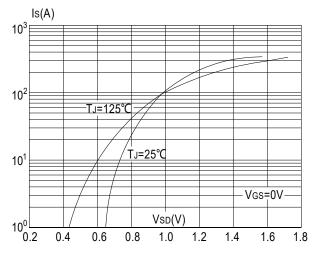


Figure 6: Capacitance Characteristics

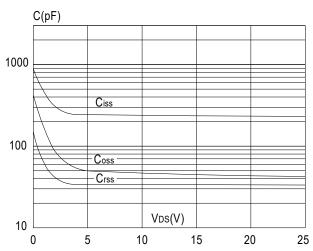




Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

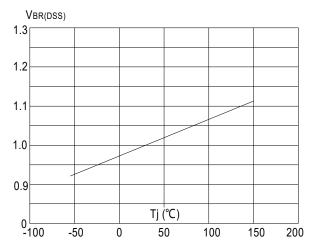


Figure 8: Normalized on Resistance vs. Junction Temperature

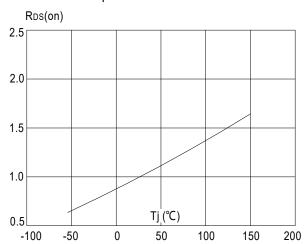


Figure 9: Maximum Safe Operating Area

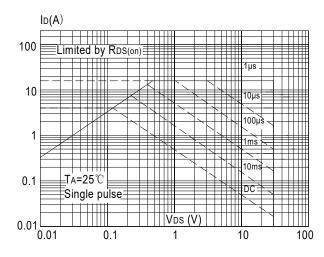


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

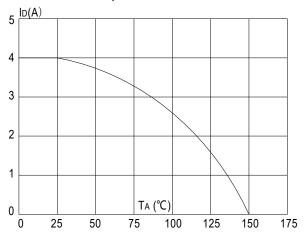
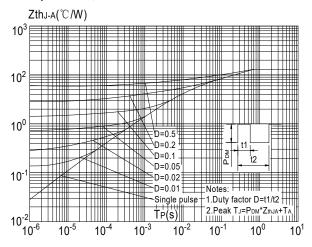
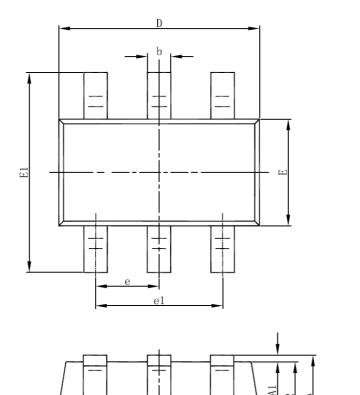


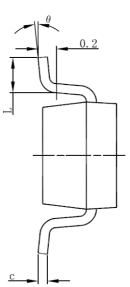
Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient





SOT-23-6L Package Information





Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

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